84254

S/076/60/034/009/019/022 B015/B056

24.7700 AUTHORS:

Sotnikov, V. S. and Belanovskiy, A. S.

TITLE:

Ion Adsorption of Some Metals During the Etching and the

Washing of Silicon

PERIODICAL:

Zhurnal fizicheskoy khimii, 1960, Vol. 34, No. 9,

pp. 2110-2114

TEXT: The electrical properties and the stability of crystalline semiconductor diodes and triodes essentially depends on the surface of the
semiconductor. V. I. Lyashenko and I. I. Stepko (Ref. 1) investigated
the adsorption of some substances, as well as their influence upon the
surface charge and conductivity of semiconductors. As the hydrofluoric
and nitric acids, the lyes, and also the rinsing water used for silicon
etching may contain admixtures such as iron, copper, and other heavy
metals in quantities from 1.10-5 to 1.10-3%, the adsorption of Cu, Ag,
Au, In, Sb, P, Fe, Zn, Rb, and Na on the surface of the silicon was
investigated with the aid of the corresponding radioisotopes. As samples,
p-type silicon foils were used, which were etched in the etching solutions

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Ion Adsorption of Some Metals Buring the Etching and the Washing of Silicon

S/076/60/034/009/019/022 B015/B056

considerably reduces the number of elements adsorbed on the silicon surface (Table 4), and that in this way the semiconductor surfaces may be purified. There are 2 figures, 4 tables, and 6 references: 2 Soviet and 4 US.

SUBMITTED:

January 15, 1959

X

Card 3/3

X

Adsorption of ...

S/076/61/035/003/003/023 B121/B203

germanium metal or germanium monoxide formed besides  ${\rm GeO}_2$  in the etching of the germanium surface with  ${\rm H_2O}_2$  acts as electron source on the germanium surface. The derivatives of divalent germanium are strong reducing agents, especially in the hydrated form. Hydrated germanium monoxide reduces the metals from the solution with simultaneous conversion to germanium dioxide according to the equation:

 $GeO + H_2O + Cu^{++} \longrightarrow GeO_2 + 2H^+ + Cu$  (3).

The separation of metals on the germanium surface was also microphotographically examined under an electron microscope. At a metal concentration in the solution of  $10^{-5}-10^{-2}\%$ , adsorption attains a value of  $10^{16}-10^{18}$  at/cm<sup>2</sup> of the germanium surface. There are 5 figures, 1 table, and 6 references: 3 Soviet-bloc and 3 non-Soviet-bloc. The three references to Englishlanguage publications read as follows: E. Clark, Phys. Rev., 91, 765, 1953; J. Law, J. Phys. Chem., 59, 67, 1955; S. Eriksen, H. Statz, J. Appl. Phys., 28, 1, 1957.

SUBMITTED:

April 12, 1959

Card 2/2

21981 \$/020/61/137/005/025/026 B103/B208

Adsorption of ions of some metals ...

publications. The authors used in their experiments polished laminae, 3 x 3 x 0.25 mm, from germanium and silicon of the n- and p-type. They were oriented in the plane 111, and had a resistivity of 15 Ohm cm. The following etching reagents were used: 30%  $\rm{H}_{2}\rm{O}_{2}$  and 10% KOH solutions, and and HNO3(60%) in a ratio of 1:4, in which radioa mixture of HF (42%) active indicators were introduced in the form of nitrates and chloric salts. The specific activity of the solutions in the individual experiments ranged from 0.1 to 5 m curies/ml. The activity of the etching reagent was first determined 0.01 ml of it were placed into a square cavity  $(3 \times 3 \text{ mm})$  of the paraffin layer on a little aluminum dish, and the activity measured considering the autoabsorption of the B-radiation in the liquid. In the following the activity of one side of the sample (the other side was polished) was determined at equal dimensions. Ge and Si were etched in an aliquot of the etching reagent for 3.0 min at room temperature in a HF-NHO, mixture, and by heating in H,0, and in KOH. The rest of the radioactive corrosive was rinsed from the surface of the samples with ethanol, and the activity of the samples was measured after drying on filter paper. The results for Ge are summarized in Table 1. They indicate that at the Card 2/8

21981 \$/020/61/137/005/025/026 B103/B208

Adsorption of ions of some metals ...

Phys.Rev., 95, 1, 284, 1954).

organic complex formers are most suitable for this purpose, since their traces may be washed off by high-purity organic solvents (CCl<sub>4</sub>, chloroform, benzene, and others). The use of water and, as a result, an additional contamination by adsorption could thus be avoided. Treatment of pn-junctions of Si with acetonitrile reduced the inverse current in the collector to 1/2 - 1/4, and increased the stability of the device. There are 3 figures and 6 references: 3 Soviet-bloc and 3 non-Soviet-bloc. The 3 most recent references to English language publications read as follows: J.T. Law (Ref. 1: J. Phys. Chem., 59, 1, 67, 1955), J.T. Law, P.S. Meigs (Ref. 2: App. Phys., 26, 10, 1265, 1955), E.Clarke (Ref. 4:

PRESENTED:

September 9, 1960 by A.N. Frumkin, Academician

SUBMITTED:

September 20, 1960

Card 4/8

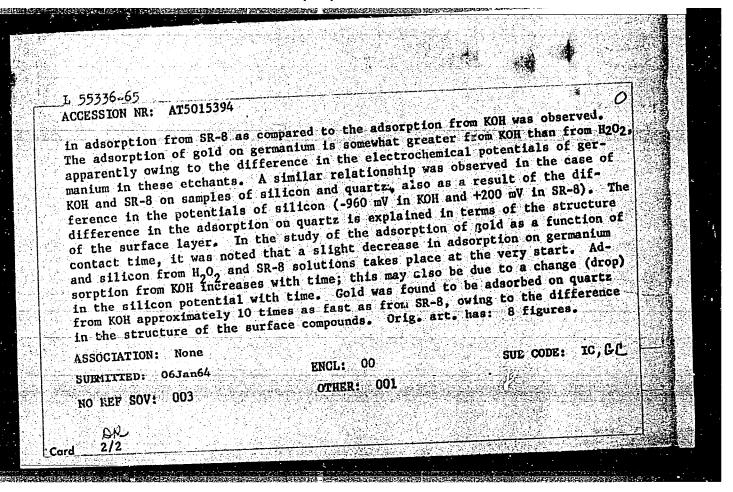
SOTNIKOV, V.S.; BELANOVSKIY, A.S.; NIKISHOVA, F.B.

Adsorption of ions of certain metals from water during silicon washing. Part 4. Radiokhimita 4 no.6:725-731 \*62. (MIRA 16:1) (Metals) (Silicon) (Adsorption)

EWP(e)/EWT(m)/EWP(1)/T/EWP(1)/EWP(b) Pq-4 IJP(c) GS/WH ACCESSION NR: AT5015393 UR/0000/65/000/000/0149/0154 541.103:54-128.4 :545.289+546.28-121+533.62 AUTHOR: Sotnikov, V. S.: Belanovskiy, A. S. TITLE: Adsorption of gold from aqueous solutions on germanium, silicon, and quartz during their washing SOURCE: AN SSSR, Otdeleniye obshchey 1 tekhnicheskoy khimii. Soosazhdeniye i adsorbtsiya radioaktivnykh elementov (Coprecipitation and adsorption of radioactive elements). Moscow, Izd-vo Nauka, 1965, 149-154 TOPIC TAGS: gold adsorption, germanium washing, silicon washing, quartz washing, Freundlich equation, chemical etching ABSTRACT: A study of the adsorption of gold on germanium, silicon, and quartz from aqueous solutions showed that it increases with the time of contact between the samples and the solution, is proportional to the Au content in solution at low concentrations ( $10^{-7}$  -  $10^{-4}$ %), and obeys the Freundlich equation (n = kc%). The desorption of gold in water at room temperature and at the boiling point is only partial, indicating that gold is strongly bound to the surface of Ge, Si, and quartz. Gold separates in the elemental state on germanium and is adsorbed primarily in the ionic state on silicon and quartz; in the case of the latter two add

55337-65	6	
orbents, the mechanism may ing into the structure of the nitial adsorption of gold on the treatment with the etcha	nvolve displacement of H <sup>†</sup> ions from OH groups enter-hydrated surface compounds. Differences in the silicon and quartz are apparently due to the fact strong structure icon. It is postulated that the amorphous structure icon. It is postulated that the amorphous structure irtz adsorbs gold to a lesser degree than does the irtz adsorbs gold to a lesser degree than does the asimilar relationship is observed in the adsorption a similar relationship is observed.	
ASSOCIATION: None SUBMITTED: 050ct63	ENCL: 00 SUB CODE: IC, G.C.	
NO REF SOV: 005	OTHER: 003	
	. 1.하이 아랫 아름이 가득되었습니다. 하는 하는 하는 하는 아무리는 이 사람들이 하는 것이다. 하는 하는 아무리는 이 아름다면 하는데 아무리를 하는데 하는데 되었다.	

L 55336-65 FWP(e)/EWT(m)	/EWP(1)/T/EWP(t)/EWP(t) Pq-4 IJP(c) JD/ /
ACCESSION NRI AT5015394	UR/0000/65/000/000/0154/0158 541.183.5:54-128.4:54-145.2:621.79.025:546.289+ 546.28+666.192
AUTHOR: Sotnikov, V. S.; Be	나이지 않는 사람들은 살아지지 않았다면 그 회장에는 얼마를 하는 것이 되었다면 하는 것이 되었다. 그 사람이 있다는 이 바람이 없다.
TITLE: Adsorption of gold fetching of germanium, silico	rom hydrogen peroxide, KOH, and SR-8 during chemical  n, and quartz
adsorbtsiya radioaktivnyku s	obshchey I tekhnicheskoy khimii, Soosazhdeniye i lementov (Coprecipitation and adsorption of radio- zd-vo Nauka, 1965, 154-158
chemical etching, hydroliuo	n, germanium etching, silicon etching, quartz etching, ic acid, nitric acid, potassium hydroxide, hydrogen
tration in the solution and	gold was studied as a function of the gold concen- of the time of contact between the samples and the 20, and KOH on germanium and KOH and SR-8 (1 pt. HF the adsorption of gold increases in proportion to ns from 10-6 to 10-7. On quartz, a slight increase



59594-65 EWT(m)/EWP(t)/EWP(b) IJP(c) J CCESSION NR: AP5017459 UR/002	D 0/65/162/005/1105/1108 //	
UTHOR: Sotnikov, V. S.; Belanovskiy, A. S.		
ITLE: Adsorption of the ions of certain met	als from electrolytes during etchi	.ng
OURCE: AN SSSR. Doklady, v. 162, no. 5, 196	5, 1105-1108	74 E
COPIC TAGS: germanium, silicon, quartz, ion equation	adsorption, etching, Freundlich	
ABSTRACT: The article discusses the adsorptions from the following etchants: CP (1:4 mix (OH) on the surface of Ge, Si, and quartz, and adsorption was studied as a function of the cand of the time of contact between the sample isotherms obtained obey the Freundlich equations are tall varies with the type of solution in which the it was 1-2 orders of magnitude greater in KO	30% H <sub>2</sub> O, on the surface of Ge. content of these ions in the solutions and the solutions. The adsorption over a wide concentration rangulated. The degree of adsorption accurs: for example,	ions ion e;
ard 1/2		

ation of the adsorption mechan mount of adsorbed substance whereater than in the case of the is present in the highest vandeed, the adsorption on quark the value corresponding to a machat the conduction type (n or of the elements studied. Orig	ionic state. For institute the state, only ionic z was lower than on Ge molayer (about 1015 atc.	ance, on quartz, in adsorption can occur or Si, and did not oms/cm <sup>2</sup> ). It was also t affect the adsorption 2 tables.	ar; exceed so found tion
			P
ASSOCIATION: None	ENCL: 00	SUB CODE: IC	
UBMITTED: 02Dec64 O REF SOV: 004	ENGL: 00 OTHER: 004	SUB CODE: AC //	

L 39035-66 EMP(e)/FMT(m)/T/EMP(t)/ETT IJP(c) WH/DS/JD

ACC NR: AP6022875 SOURCE CODE: UR/0186/66/008/002/0171/0182

AUTHOR: Sotnikov, V. S.; Belanovskiy, A. S.

ORG: none

TITIE: On the adsorption of ions of certain metals from electrolytes on the surface of germanium, silicon, and quartz | 5

SOURCE: Radiokhimiya, v. 8, no. 2, 1966, 171-182

TOPIC TAGS: germanium, silicon, quartz, adsorption, etched crystal, copper, silver, gold, indium, antimony, zinc

ABSTRACT: The paper offers data on the adsorption of copper, silver, gold, indium, antimony, and zinc ions from the chemical etchants CP (a 1:4 mixture of 49% HF and 65% HNO<sub>3</sub>) and 20% KOH on the surface of germanium, silicon, and quartz, and also from 30% H<sub>2</sub>O<sub>2</sub> on the surface of germanium, as a function of the content of these metals in the solution and of the etching time. The temperature was 20°C for CP, 107°C (boiling point) for KOH, and 104°C (boiling point) for H<sub>2</sub>O<sub>2</sub>. The adsorption on quartz was studied in order to elucidate the mechanism of adsorption on silicon, whose surface is usually coated with a thin film of SiO<sub>2</sub>, but the results are also independently significant in view of the wide use of quartz apparatus. It is shown that at a content of the above impurities from 10-5 to 10-1% in the etchants, the adsorption values

Card 1/2

UDC: 541.183.5:54-128.4

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JD/JG EWI(m)/EWP(t)/ETI ·IJP(c) L 05206-67 SOURCE CODE: UR/0075/66/021/006/0754/0757 ACC NR: AP7000758 Sotnikov, V. S. Korolev, N. V. Shumova, V. V. and Forozova, M. N. AUTHOR: ORG: none TITLE: Use of an emission microspectral method in the analysis of alloys for semiconductor devices SOURCE: Zhurnal analiticheskoy khimii, v. 21, no. 6, 1966, 754-757 TOPIC TAGS: emission spectrum, indium alloy, gallium alloy, gold alloy اله ABSTRACT: A microspectral method for the analysis of the In - Au - Ga and other

ABSTRACT: A microspectral method for the analysis of the In - Au - Ga and other alloys in specimens weighing less than 0.5 mg is examined. Alloy specimens in tablets 50X150 microns in size were placed on a polished surface of a glass bar, and then the specimens were covered with a copper plate about 1 mm thick which was tapped lightly with a hammer so that the specimens were secured to the surface of the copper plate. Then tablets were secured to the surface layer of the plate. Fellets of standard alloys were similarly secured to a copper plate, and a microspectral analysis was made. Copper vice 0.6 mm in diameter with ends cut at a 130° angle served as the electrode. The distance between one of the electrodes from the surface of the specimen was 1 mm; the second electrode was connected to the copper plate. Orig. art. has: 2 figures and 1 table. [JPRS: 37,177] SUB CODE: 11,20/ SUBM DATE: 02Jun65 / CRIG REF: CO2

Cord 1 1 gd

0923 543-42

ACC NR: AP7007204

SOURCE CODE: UR/0186/66/008/006/0617/0621

AUTHOR:

Sotnikov, V. S.; Belanovskiy, A. S.; Trakhtenberg, A. D.

ORG: none

TITIE: On the adsorption of metal ions from  $\rm H_2O_2$  and KOH on the surface of electron-hole germanium and silicon junctions

SOURCE: Radiokhimiya, v. 8, no. 6, 1966, 617-621

TOPIC TAGS: adsorption, hydrogen peroxide, potassium hydroxide, pn junction

ABSTRACT: The adsorption of Cu, Ag, Au and In ions from H2O, H2O2 and KOH on parts making up a germanium p-n-p junction (TM-5) and silicon p-n-p (P104-106) and n-p-n (P 101-103) junctions was studied. It is shown that a considerable contamination of the solutions with elements constituting the junction takes place during etching (the amount of impurities in the solutions increases by 2 to 3 orders of magnitude). Thus, adsorption on the junctions is very important, since in contrast to germanium and silicon crystals, etching of the junctions occurs in a solution with a high impurity content. Cu and In impurities, adsorbed by the surface of junctions of types P101-103 and TM-5, cause a considerable increase of I<sub>CO</sub> (zero collector current). The various distributions of the adsorbed impurities on different parts of junctions of various types were studied by means of autoradiographic photographs. Orig. art. has: 3 tables.

SUB CODE: 07/ SUBM DATE: 21Jun65/ ORIG REF: 004/ OTH REF: 003

ACC NR: AP7007205

SOURCE CODE: UR/0186/66/008/006/0691/0692

AUTHOR: Sotnikov, V. S.; Kuznetsova, M. I.

ORG: none

TITLE: Adsorption of indium, cobalt and zinc ions from acetone on the surface of graphite, germanium, silicon and quartz

SOURCE: Radiokhimiya, v. 8, no. 6, 1966, 691-692

TOPIC TAGS: adsorption, indium, cobalt, zinc, graphite, quartz, germanium, silicon

ABSTRACT: The adsorption of In, Co and Zn from acetone on graphite, germanium, silicon and quartz surfaces was studied as a function of concentration of the impurities and time of contact with the solution at concentrations of 10<sup>-4</sup>-10<sup>-2</sup>% with the aid of In<sup>114</sup>, Co<sup>00</sup> and Zn<sup>05</sup> isotopes. It is shown that the adsorption of indium on graphite, germanium, silicon and quartz obeys the Freundlich equation up to a concentration of 210<sup>-3</sup>%, and the adsorption of zinc on Ge and quartz, up to 10<sup>-2</sup>%. Adsorption saturation for Zn and Co on Ge, Si and SiO<sub>2</sub> takes place in 5-10 min, and for indium in less than 1 min. The lack of adsorption saturation in the case of graphite plates (which were porous) is attributed to diffusion processes. Values of the adsorption obtained were 10<sup>14</sup>-5 x 10<sup>15</sup> atoms per cm<sup>2</sup>. Orig. art. has: 2 figures.

SUB CODE: 07/ SUBM DATE: 03Jun66/ ORIG REF: 001

Card 1/1

UDC: 541.183:546.3

DENISENKO, P.A.; MURZIN, L.M.; SOTNIKOV, Ya.I., red.; QUIMOV, A.V., tekhn.red.

[Operations of the heat and electric power plant of the Gorkiy
Antomobile Plant] Iz opyta raboty TETa Gor'kovskogo avtomobil'nogo zavoda. Moskva, TaBTI avtomobil'noi promyehl., 1958. 40 p.

(Gorkiy--Steam power plants)

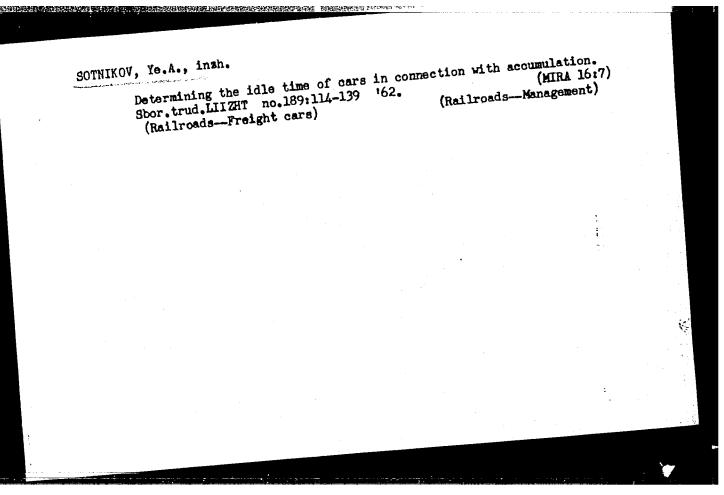
(Gorkiy--Steam power plants)

SKRYNNIK, Vladimir Nikitovich; SOTNIKOV, Ya.I., ved. red.; PONUROV, M.P., red.

[Design of automatic lines consisting of machine-tool units; survey of foreign engineering] Proektirovanie avtomaticheskikh survey of foreign engineering (MIRA 17:7)

"Economics of classification stations and organization of car flows" by [kand.tekhn.muk] P.S.Sokolov. Reviewed by E.A.Sotnikov. Vest. TSNII MFS 21 no.1:62-64, '62. (MIRA 15:2)

1. Oktyabr'skaya zheleznaya doroga, stantsiya Mga. (Railroads—Hump yards)



SOTNIKOV, Yevgeniy Aleksandrovich; UGRYUMOV, Georgiy Arkad'yevich;
FARDEROV, Ya.D., inzh., retsenzent; PREDE, V.Yu., inzh.,
red.; VOROTNIKOVA, L.F., tekhn. red.

[Operational planning of the work in a railroad station]
Operativnoe planirovanie raboty na stantsii. Moskva, Transzheldorizdat, 1963. 56 p.

(Railroads—Management)

(MIRA 16:3)

S/0280/64/000/004/0187/0190

ACCESSION NR: AP4044838

AUTHOR: Dolyatovskiy, V. A., Sotnikov, Ye. M.

TITLE: One class of teaching machines

SOURCE: AN SSSR. Izvestiya. Tekhnicheskaya kibernetkia, no. 4, 1964, 187-190

TOPIC TAGS: teaching machine, learning process, computer programming, teaching

ABSTRACT: The authors discuss the teaching process and examine the general theory of program teaching machines. They recommend that the program of a teaching machine should explain the concepts studied from many aspects, point out to the student his mistakes in the process of learning, and provide means for correcting mistakes and for the formation of logical thought. Such requirements are satisfied by a machine whose teaching program is divided into several branches and which also has a controlling and correcting program. The program for machines of this type has a definite structure whose elements are specific concepts, the branching system of the program, and the system for evaluating the answers. Such machines can be constructed quite simply on the basis of a generalpurpose digital computer. A relatively simple machine of this type is briefly described. Card 1/3

ACCESSION NR: AP4044838

Its block diagram is shown in Fig. 1 of the Enclosure. The machine was built in the form of a table model, and can teach 6 persons a section per hour. A teaching machine of this type can find wide use in colleges for teaching and testing purposes, as well as for investigating various problems in teaching by machines. Orig. art. has: 2 figures and 4 formulas.

ASSOCIATION: none

SUBMITTED: 21Nov63

ENCL: 01

SUB CODE: DP

NO REF SOV: 005

OTHER: 000

Card 2/3

ACCESSION NR: AP4044838

ENCLOSURE: 01

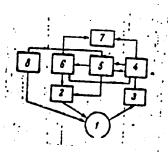


Fig. 1. Block diagram of a teaching machine. 1 - student, 2 - unit giving the teaching program, 3 - device for accepting the answers, 4 - unit for logical analysis and decision, 5 - controlling device, 6 - timing unit, 7 - unit indicating the results, 8 - unit giving the correcting program.

Card 3/3

L 5128-66 EWT(d)/BXT/EWP(1) IJP(c) BB/GG ACCESSION NR: AP5026302 UR/0144/65/000/008/0881/0890 681.142+62-50 AUTHOR: Dolyatovskiy, V. A. (Aspirant); Sotnikov, TITLE: Certain principles of learning and machine teaching SOURCE: IVUZ. Elektromekhanika, no. 8, 1965, 881-890 TOPIC TAGS: teaching machine, circuit design, cybernetics, learning mechanism ABSTRACT: The number of students at the institutions of higher learning of the Soviet Union increased in 1963 by 1.4 times as compared with the enrollment in 1957. This puts a great stress on the teaching staff and leads to the need for the rationalization of the teaching process. After outlining the basic principles of the learning process, the present authors describe the teaching program for the students of the Industrial Electronics course (which is the fourth in the Automation and Telemechanics curriculum) which then served as the basis for the construction of the appropriate table model electronic teaching machine. The entire course was divided into eight sections each of which was further subdivided into Card 1/2 09010222

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L 5129-66 EWT(d)/BXT/EWP(1) IJP(c) ACCESSION NR: AP5026303 UR/0144/65/000/008/0891/0894 681.142.33 AUTHOR: Dolyatovskiy, V. A. Aspirant); Sotnikov, Ye. M. (Assistant) TITLE: Electromechanical teaching machine SOURCE: IVUZ. Elektromekhanika, no. 8, 1965, 891-894 TOPIC TAGS: cybernetics, teaching machine, semiconductor device, algorithm ABSTRACT: In recent years, the teaching process has been investigated from the viewpoint of cybernetics. The theoretical foundations of algorithmic formulation of the learning processes were laid down earlier by various authors. The realization of the proposed algorithms was carried out on various machines developed for that purpose. The present article describes one of such machines which was developed and put to use by the authors and was shown at the VDNKh exposition of teaching machines in 1964. The programmed course "Industrial Electronics" was divided into 24 sections. The associated 15 - 20 control questions approached the programmed materials from various angles. The material

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	onance" field at the surface.  18, was parallel to the speciments of outer field to the speciments.		ld,
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SOTNIKOV, Ye.V.

Evaluation through work of students! knowledge, skills, and habits. Politekh. obuch. no.7:50-51 J1 :59. (MIRA 12:9)

1.Srednyaya shkola No.3. g.Vladimir. (Vladimir--School reports)

SOTNIKOV, Yu.M., inzh.

Use of epoxy resins at the Zhdanov shipyard. Biul. tekh.-ekon. inform, Tekh. upr. Min. mor. flota 7 no.4:78-85 '62. (MIRA 16:4)

1. Zhdanovskiy sudoremontnyy zavod.
(Zhdanov—Shipyards)
(Epoxy resins)

ACC NR: AP6034918

SOURCE CODE: UR/0419/66/000/003/0107/0108

AUTHOR: Rubinchik, Ya. S.; Sotnikov-Yushik, Yu. M.

ORG: Institute of General and Inorganic Chemistry, AN BSSR (Institut obshchey 1 neorganicheskoy khimii AN BSSR)

TITLE: Study of reactions of rare earth oxides with ferric oxide by means of IR spectra

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SOURCE: AN BSSR. Vestsi. Seryya khimichnykh navuk, no. 3, 1966, 107-108

TOPIC TAGS: yttrium compound, ytterbium compound, samarium compound, iron oxide, IR spectrum

ABSTRACT: Yttrium, ytterbium and samarium oxides were reacted with Fe<sub>2</sub>O<sub>3</sub> at 810-1200° and the sintered products were analyzed by means of IR spectra in the 400-650 cm-1 range. The spectra of the oxides, perovskites and garnets containing different rare earth ions were very similar, indicating a slight influence of the element on the IR spectrum of the compounds. The character of the spectrum of the products changes with the firing temperature. The spectra obtained confirm earlier findings for the Y203+Fe203 system, viz., that at relatively low temperatures in 3:5 oxides mixtures, the reaction forms a perovskite which, as the temperature is raised further, reacts with excess Fe<sub>2</sub>0<sub>3</sub> to form the end product, a garnet. Orig. art. has: 1 figure.

SUB CODE: 07/ SUBM DATE: none/ ORIG REF: 002/ OTH REF: 002

Card 1/1

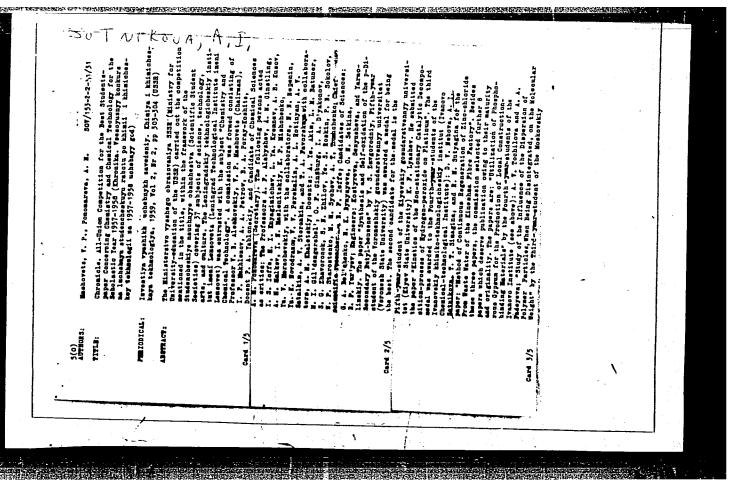
Under joint management. Sov.torg. 36 no.12:24-25 D '62.

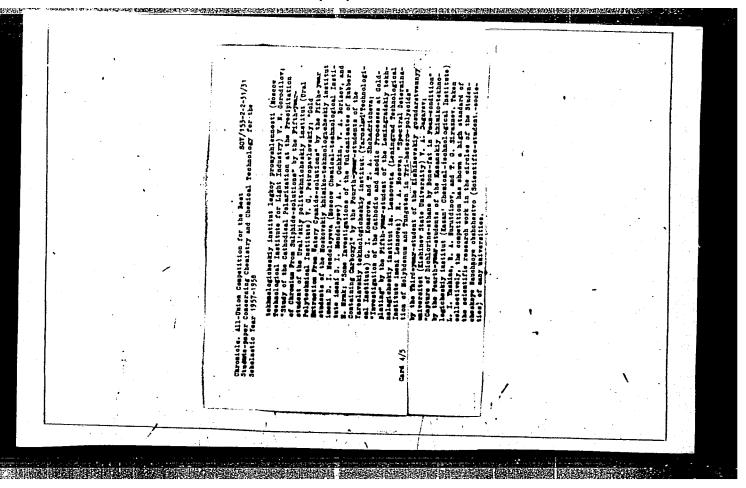
(MIRA 16:1)

1. Nachal nik planovogo otdela Voronezhskov gorodskov torgovov

1. Nachal'nik planovogo otdela Voronezhskoy gorodskoy torgovoy organizatsii po torgovle pishcheproduktami.

(Voronezh-Grocery trade)





SOTNIKOVA, A. H., AMBARTIKOV, I. M., DANDUROV, YU. V., KHVESHCHENKO, E. N.

"A study of the strains of tick encephalitis isolated in the foci of the Primorye region in 1956-1957." p. 54

Desystoye Soveshchaniye po parazitologicheskim problemam i prirodnoochagovym boleznyam. 22-29 Oktyabrya 1959 g. (Tenth Conference on Parasitological Problems and Diseases with Natural Foci 22-29 October 1959), Moscow-Leningrad, 1959, Academy of Medical Sciences USSR and Academy of Sciences USSR, No. 1 254pp.

SOTNIKOVA, A.N.; SOLDATOV, G.M.

Isolation of the tick-borne encephalitis virus from the grosbeak Eophona personata magnirostris Hart. Dokl. Irk. gos. nauch.-issl. protivochum. inst. no.5:28-29 '63 (MIRA 18:1)

Case of isolation of the neurovirus from chiggers. Ibid.:30

SOTNIKOVA, A.N.

Characteristics of tick-borne encephalitis strains isolated in Characteristics of the Maritime Territory. Trudy VladJEMG no.2;24-27 162. (MIRA 18:3)

1. Iz Frimorskov krayevov protivochumnov stantsii.

SOTNIKOVA, A.N.; SOLDATOV, G.M.

Isolation of the virus of tick-borne encephalitis from the flea Ceratophyllus tamias wagn. Med. paraz. i paraz. bol. 33 no.5:622-624 S-0 164. (MIRA 18:4)

1. Primorskaya krayevaya protivochumnaya stantsiya, Ussuriysk.

SOTNIKOVA, A.N.; SOLDATOV, G.M.

Isolation of tick-borne encephalitis virus in jays. Med. paraz. i paraz. bol. 34 no.1:114-115 Ja-F '65.

(MIRA 18:8)

1. Primorskaya krayevaya protivochumnaya stantsiya, Ussuriysk.

EWT(m)/BDS/ES(b)--AFFTC/ASD--RM/K

L 10777-63

ACCESSION NR: AP3003923

5/0205/63/003/004/0504/0507

AUTHOR: Sotnikova, A. P.; Sy\*tinskiy, I. A.

56 -5

TITLE: Effect of total-body x-irradiation on the content of gamma amino butyric acid in brain tissue

SOURCE: Radiobiologiya, v. 3, no. 4, 1963, 504-507

TOPIC TAGS: x-irradiation, x-radiation, gamma amino butyric acid, brain tissue, radiation sickness, sodium amobarbital, glutamic acid, sodium amytal, S-2-amino-ethylisothiuronium, cystemines, antiradiation preparation

ABSTRACT: Attempts have been made to correlate the effect of total-body x-irradiation (dosage 1000 r) with the level of gamma amino butyric acid (GABA) in the brain and to estimate the efficacy of survival compounds (e.g., sodium amytal, S-2-aminoethylisothiuronium cystamine) on the organism. The effects of the compounds were investigated by using the GABA as a biochemical index of the processes occurring in the central nervous system during irradiation. An RUM-ll unit (current, 20 mamp; voltage, 180 kv; filters, 0.5-mm Cu and 1.0-mm Al; air dose, 46.7 r; focal length, 30 cm) was employed to deliver a total-body x-irradiation

Card 1/2

L 10777-63 ACCESSION NR: AP3003923 of 1000 r on white rats. No change was detected in the level of GABA and glutamic acid in the brain of the irradiated animals. Application of S-2-aminoethylisothiuronium (40 mg/100 g) evoked spasmodic phenomena with lethal results, attributable to a 22 drop in the GABA level and a 35 drop in the glutamic acid level. The introduction of sodium amobarbital (7 mg/100 g) and cystamine (8 mg/100 g) caused no change in the level of GABA and glutamic acid in the brain of the animals. Orig. art. has: 1 table. ASSOCIATION: Leningradskiy gosudarstvenny\*y universitet im. A. A. Zhdanov (Leningrad State University) SUBMITTED: 05Ju162 DATE ACQ: 15Aug63 ENCL: 00 SUB CODE: NO REF SOV: 004 OTHER: 010

VASIL'TSOV, V.D.; VOLCHENKO, M.Ya.; GERTSOVICH, G.B., kand.ekon. nauk; ZHARKOV, Ye.I.; KONOVALOV, Ye.A., kand. ekon. nauk; MATVIYEVSKAYA, E.D.; OLEYNIK, I.P., kand. ekon. nauk; RAYEVSKAYA, E.S.,; SKVORTSOVA, A.I.; SOKOLOVA, N.V.; SOTNIKOVA, I.A.; TANDIT, V.S.; TRIGUBENKO, M.Ye.; FIRSOVA, Yu.V.; SHABUNINA, V.I.; YUMIN, M.N.; STOROZHEV, V.I., kand. istor. nauk, red.; LEPNIKOVA, Ye., red.; STIRNOV, G., tekhn. red.

[Economy of the people's democracies in figures for 1960] Ekono-

[Economy of the people's democracies in figures for 1960] Ekonomika stran sotsialisticheskogo lageria v tsifrakh 1960 g. Pod red. G.B.Gertsovicha, I.P.Oleinika, V.I.Storozheva. Moskva, Izdvo sotsial'no-ekon. lit-ry, 1961. 238 p. (MIRA 15:4) (Communist countries—Economic conditions)

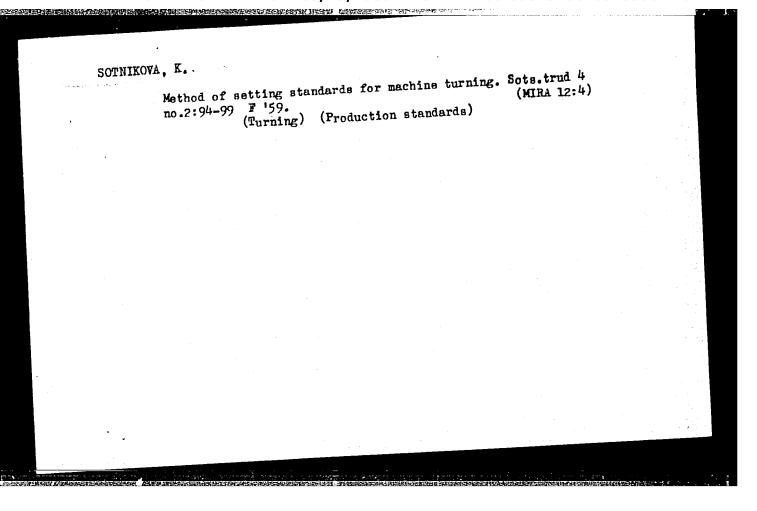
VASIL'TSOV, V.D.; VOLODARSKIY, L.M.; VOLCHENKO, M.Ya.; GALETSKAYA, R.A.; IROV, N.I.; KARINYA, L.F.; KONOVALOV, Ye.A.; MATVIYEVSKAYA, E.D.; PETRESKU, M.I.; RUDAKOV, Ye.V.; SAYFULINA, L.M.; SKVORTSOVA, A.M.; SOKOLOVA, N.M.; SOTNIKOVA, I.A.; STOLPOV, N.D.; SURKO, Yu.V.; TEN, V.A.; TRIGUHENKO, M.Ye.; FIRSOVA, Yu.V.; SHABUNINA, V.I.; YUMIN, M.N.; RYABUSHKIN, T.V., doktor ekon. nauk, otv. red.; ALAMPIYEV, P.M., red.; PAK, G.V., red.; GERASIMOVA, D., tekhn.red.

CONTROL OF THE SECOND OF THE S

[Ecoromy of socialist countries, 1960-1962] Ekonomika stran sotsializma, 1960-1962gg. Moskva, Izd-vo "Ekonomika," 1964. (MIRA 16:12) 261 p.

1. Akademiya nauk SSSR. Institut ekonomiki mirovoy sotsialisticheskoy sistemy.

(Communist countries--Economic conditions)



GRANOVSKIY, Ye.; SOTNIKOVA. K.

New book on technical standardization (Technical standardization at a machinery manufacturing plant by M. Shadmazarova). Sots. trud. 4 no.10:155-158 0 '59

(Machinery industry--Production standards)

(Machinery industry--Production standards)

POGREBATIKO, Ye.; SOTNIKOVA, K.

Instruments for determining efficient systems of metal cutting accepted at the all-union competition. Biul.nauch.inform.itrud accepted at no.6:141-51 159.

i zar.plata no.6:141-51 (Metal cutting)

SOTNIKOVA, K.A., kand. med. nauk; KRASIKOVA, V.A., kand.med. nauk

Indices of arterial pressure in healthy children during the
first three years of life. Vop okhr. materin. dets. 8 no.1:
56-59 '63

1. Iz kliniki rannego vozrasta (zav. - prof. N.R.Shastin)
Nauchmo-issledovatel skogo pediatricheskogo instituta (dir.
kand. med. nauk V.P.Spirina) Ministerstva zdravookhraneniya
RSFSR.

SHASKOL'SKIY, B.V., kand. tekhn. nauk; SOTNIKOVA, K.F., inzh.;
GAVRILIN, Ye.F.; LUBKOV, A.N.; SAPOZHNIKOV, V.M.; ZHUCHENKO,
L.F.; CHIGIRINA, N.I., tekhnik; ZHARIKOV, I.P., inzh.;
CHERTISHCHEVA, A.Ye.; SHAPOVALOV, V.K., tekhnik; MOROZOV, A.M.,
inzh.; SLIVKO, S.V., tekhnik; CHERNAVSKIY, G.N., kand. tekhn.
nauk; STRUZHESTRAKH, Ye.I., inzh., ed.; EL'KIND, V.D., tekhn.
red.; DEMKINA, N.F., tekhn. red.

[General norms for time and machining conditions used in the industry for machining on automatic lathes; mass, large-lot and lot production]Obshchemashinostroitel'nye normativy vremeni i rezhimov rezaniia na tokarno-avtomatnye raboty; massovoe, krupnoseriinoe i seriinoe proizvodstvo. Moskva, Mashgiz, 1962. (MIRA 15:12)

1. Moscow. TSentral noye byuro promyshlennykh normativov po trudu. (Turning--Production standards)

3.5 EWP(e)/EWT(m)/EWP(t)/ETI/EWP(k) IJP(c) JD/JG/AT/WH 38308-66 SOURCE CODE: UR/0122/66/000/004/0064/0069 ACC NRI AP6012745 AUTHORS: Romanov, K. F. (Candidate of technical sciences); Sotnikova, K. F. (Engineer) ORG: none  ${\mathcal S}$ TITLE: The effect of the technological conditions of processing on the rate of cutting during the turning of parts made from heat-resistant and titanium materials SOURCE: Vestnik mashinostroyeniya, no. 4, 1966, 64-69 TOPIC TAGS: heat resistant material, heat resistant steel, titanium containing alloy, metalworking, metalworking machinery ABSTRACT: Corrective coefficients are applied to the normal cutting rate for the turning of machine parts made from heat-resistant materials. These coefficients take into account the effect of the technological working conditions; they are developed on the basis of studies performed both in laboratories and in industry. Note is made of some discrepancies between the cutting rates predicted from laboratory tests and those recorded in actual industrial conditions. Turnings of various machine parts and various types of cuttings are compared with respect to feed rate. Several parameters were treated as variables, including the thermal processing of the material, the geometric dimensions of the material, the grade and type of material, and the mechanical properties of the material. Note is also made of the UDC: 621.9.014.5:669.14.018.44 Card 1/2

RUDNEVA, L.N., inzh.; SOTNIKOVA, K.V., inzh.

Manifesturing targe asbestos cement sheets on automated equipment. Stroi. mat. 11 no.5:13-14 My '65. (MIRA 18:9)

BOOK CHARLES CONTROL OF CONTROL CO

SOTNIKOVA, L.G., ordinator

Blood proteins in normal and pathological pregnancy as shown by paper electrophoresis data. Kaz.med.zhur. 40 no.6:79-81 N-D '59.

(MIRA 13:5)

1. Iz kafedry akusherstva i ginekologii No.2 (zav. - prof. Kh.Kh. Meshcherov) Kazanskogo meditsinskogo instituta.

(BLOCD PROTEINS) (PREGNANCY) (PAPER KLECTROPHORESIS)

DUNAYEVA, V.G.; SOTNIKOVA, L.G.; YAKUBOVA, Z.S.

Immediate and late results of treating a threatening abortion.
Nauch. trudy Kaz. gos. med. inst. 14:421-423 '64. (MIRA 18:9)

1. II kafedra akusherstva i ginekologii (zav. - prof. Kh.Kh. Meshcherov) Kazanskogo meditsinskogo instituta.

SOTNIKOVA, L. I.

USSR/Physics - Energy levels

Card 1/1 Pub. 22 - 24/54

Authors : Krasnikov, A. I.; Sotnikova, L. I., and Orlov, L. G.

Title : Transition of the deep energetic levels of ferrous atoms during cold metal deformations

Periodical: Dok. AN SSSR 102/5, 943 - 945, June 11, 1955

Abstract : A study of the displacement of the deep energy levels, Lm& Lill of ferrous atoms is described. Effect of cold deformations on the displacement of deep energy levels of ferrous atoms is discussed. Three USSR references (1939-1946). Table.

Institute: The Institute of Metallography and the Physics of Metals of the Scientific Research Institute of Ferrous Metallurgy

Presented by: Academician G. V. Kurdyumov, February 23, 1955

LAYNER, D.I., MALYSHEVA, L.A., SOTNIKOVA, L.I.

Silicon-copper catalyzers and prospects for a considerable economy of copper. TSret. met. 33 no.8:70-72 Ag '60.

(MIRA 13:8)

(Silicon-copper alloys) (Catalysts)

S/680/61/000/020/00 /013 D204/D302

AUTHORS: Layner, D. I., Malysheva, L. A. and Sotnikova, L. 1.

TITLE : Poisons of the Cu-Si alloy catalysts

Moscow, Gosudarstvennyy nauchno issledovatel'skiy i SOURCE:

proyektnyy institut obrabotki tsvetnykh metallov. Sbornik nauchnykh trudov. no. 20, 1961, Metallovedeniye i obrabotka tsvetnykh metallov i splavov, 14-16

TEXT: The authors studied t! inhibiting effect of small additions of Pb. Sn and Bi on the stalytic activity of 10% Cu. 90% Si alleys, by measuring the productivity (in g product/kg catalyst/hr) and the percentage yield of Me\_SiCl\_ in the synthesis of

methyl chlorosilanes. The alloys were prepared, in carbon boats, from Kp1 (Kr1) silicon, MO (MO) copper, CB (SV) lead, O1 (O1) tin and spure bismuth (according to TYMXN 3153-54) (TUMKhP 3153-54), checking the composition by chemical analysis. It was found that Pb, Bi and Sn poisoned the catalyst when in quantities > 0.003,

Card 1/2

S/680/61/000/020/001/013 D204/D302

0.005 and >0.05% respectively. S. A. Golubtsov, I. V. Trofinova and No P. Lobusevich aided the authors in the chemical part of the work. There are 2 tables and 3 Soviet-bloc references.

Card 2/2

LAYNER, D.I.; MALYSHEVA, L.A.; SOTNIKOVA, L.I.

Promoting silicon-copper catalysts by antimony. Trudy
Giprotsvetmetobrabotka no.20:17-19 '61. (MIRA 15:2)
(Silicon-copper alloys) (Antimony) (Catalysts)

TURETSKAYA, R.A.; GOLUBTSÖV, S.A.; TROFIMOVA, I.V.; ANDRIANOV, K.A.; Prinimali uchastiye: LAYNER, D.I.; SOTNIKOVA, L.I.; MALYSHEVA, L.A.

> Effect of the admixture of some metals on the activity of silicon-copper alloys in the reaction with theyl chloride. Zhur.prikl.khim. 35 no.7:1496-1502 Jl 162. (MIRA 15:8)

1. Gosudarstvennyy nauchno-issledovatel'skiy i proyektnyy institut obrabotki tsvetnykh metallov (for Layner, Sotnikova, Malysheva). (Metals)

(Silicon-copper alloys) (Ethane)

MYULLER, N. N.; SOTNIKOVA, L. I.

Studying certain properties of copper cathodes deposited in presence of various surface active additives. TSvet. met. 35 no.10:29-33 0 62. (MIRA 15:10)

(Copper-Electrometallurgy)

APPROVED FOR RELEASE: 08/23/2000 CIA-RDP86-00513R001652530012-6"

MYULLER, N.N.; SOTNIKOVA, L.I.

Effect of additions of surface-active substances on the structure of cathodic copper. TSvet. met. 36 no.1:21-22 Ja '63. (MIRA 16:5) (Copper-Electrometallurgy) (Surface-active agents)

MYULLER, M.R.; SOTELKOVA, L.I.

Effect of surface-active additions on the structure of cathodic copper. Trudy Giprotsvetmotobrabotka no.24:139-145 \*65. (MIRA 18:11)

SOTNIKOVA, L.L., dots.; SEMENENKO, L.A., sudebnomeditsinskiy ekspert (Khar'kov).

How did you dare? Zdorov'e 6 no.4:24 Ap '60. (MIRA 13:8)
(ABORTION)

SOTNIKOVA, L.L., kand.med.nauk; TUNINA, E.L., kand.med.nauk (Khar'kov)

Significance of medical documentation in medicolegal expertise on living persons. Vrach. delo no.11:117-119 N '61. (MIRA 14:11) (MEDICAL JURISPRUDENCE)

MESHCHEROV, Kh.Kh.; SOTNIKOVA, L.G.

Electrophoretic study of the blood serum in normal pregnancy and late toxicosis. Nauch. trudy Kaz. gos. med. inst. 14:485-486 464. (MIRA 18:9)

1. II kafedra akusherstva i ginekologii (zav. - prof. Kh.Kh. Meshcherov) Kazanskogo meditsinskogo instituta.

SOTNIKOVA, L.G.

Comparative data on the study of glycoproteins and sialic acid of the blood serum in normal pregnancy and in late toxicosis. Nauch. trudy Kaz. gos. med. inst. 14:549-550 '64. (MIRA 18:9)

l. II kafedra akusherstva i ginekologii (zav. - prof. Kh.Kh. Meshcherov) Kazanskogo meditsinskogo instituta.

APPROVED FOR RELEASE: 08/23/2000 CIA-RDP86-00513R001652530012-6"

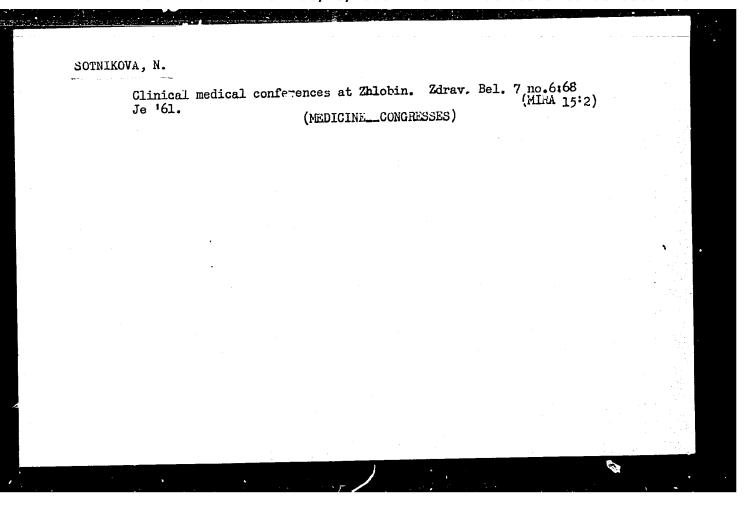
MARTYNOV, M.S.; POTAPOV, V.P., inzh., retsenzent; SOTNIKOVA, M.A., inzh., retsenzent; SHISHLYKOV, Ye.S., inzh., red.; WOROTNIKOVA, L.F., tekhn. red.

[Transportation of perishable goods] Perevozki skoroportia-shchikhsia gruzov. Moskva, Transzheldorizdat, 1963. 331 p. (MIRA 16:7)

(Railroads--Freight) (Refrigerator cars)

- 1. SOTNIKOVA, M.P.
- 2. USSR (600)
- 4. Georgiev, Emil
- 7. "Slavic alphabet before Cyril and Methodius." Reviewed by M.P. Sotnikova, Vop.ist. no. 3, 1953.

9. Monthly List of Russian Accessions, Library of Congress, APRIL 1953, Uncl.



SHMALIY, K.V.; NAKHMANSON, G.L.; MEL'HIKOV, Ye.L. (Khar'kov); BORINA, M.Ya.

(Kiyev); SOTNIKOVA, N.A.; BORSHCHEVSKIY, M.A. (Odessa)

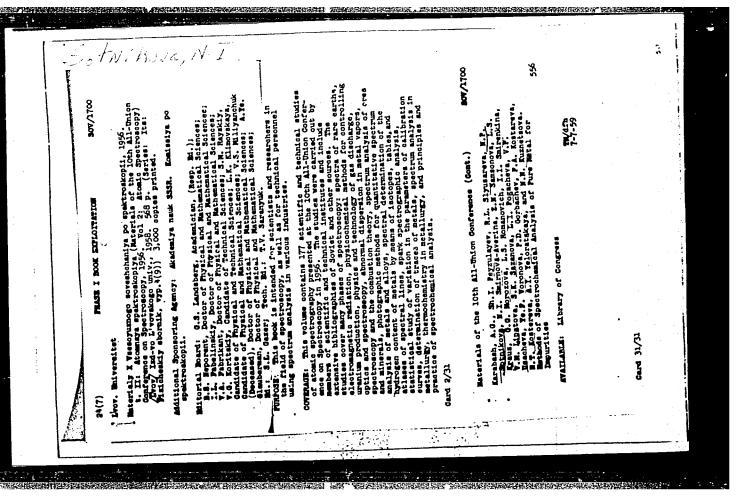
Primary drug resistance in pulmonary tuberculosis. Vrach. delo no.l:

(MINA 15:2)

98-100 Ja '62.

(TUBERCULOSIS) (BACTERIA, EFFECT OF DRUGS ON)

"APPROVED FOR RELEASE: 08/23/2000 CIA-RDP86-00513R001652530012-6



VALITOVA, F.G.; IL'YASOV, A.V.; SOTNIKOVA, N.N.; BAYGIL'DINA, S.Yu.

Electron paramagnetic resonance study of electrochemically generated radicals of some hydrazines. Zhur.strukt.khim. 6 no.5:777-779 S-0 \*65. (MIRA 18:12)

1. Institut organicheskoy i fizicheskoy khimii AN SSSR, Kazan'.

L 31461 ACC NR:	1 <u>-66</u> EWI(m)/EWP(j), AP6023114	T WW/JW/JWD/R	SOURCE CODE: UI	1/0379/66/002/001/0	142/0143
AUTHOR:	Il'yasov, A. V.; L	evin, Ya. A.; So	tnikova, N. N.;	Valitova, F. G.	85.
ORG: I	Institute of Organic Cheskoy i fizicheskoy	and Physical Che khimii AN SSSR)	mistry, AN SSSR	Kazan' (Institut	2
TITIE:	Electrochemical gen	eration of hydra	zyl radicals		
SOURCE:	Teoreticheskaya i	ek <b>sper</b> imental'na	ıya khimiya, v. 2	2, no. 1, 1966, 142	:-143
TOPIC T electro resonat	MAGS: electrochemist on spectrum, electron tor	ry, free radical paramagnetic re	l, hydrazine der esonance, redox	ivative, electrolyteaction, resonator	ric cell, -/RE-1301
B_nicr	CT: It is known that	e obtained by tr	eating the corr	esponding hydrazine	98
bility	ead dioxide or other of obtaining these re- cell containing plati	adicals by elect num electrodes.	rochemical oxide as described pre	ation. An electro. eviously, was	
placed	directly into the RE de in acetonitrile, ic solutions with a	_1301 radiospect	trometer resonat le. dioxane, alc	or. Measurements ohol, and aqueous-	
Tetreme	ethyl_ammonium iodide blyte. To improve th	and chloride we	ere used as the	guppo riting	9
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L 31461-66 ACC NR: AP6023114

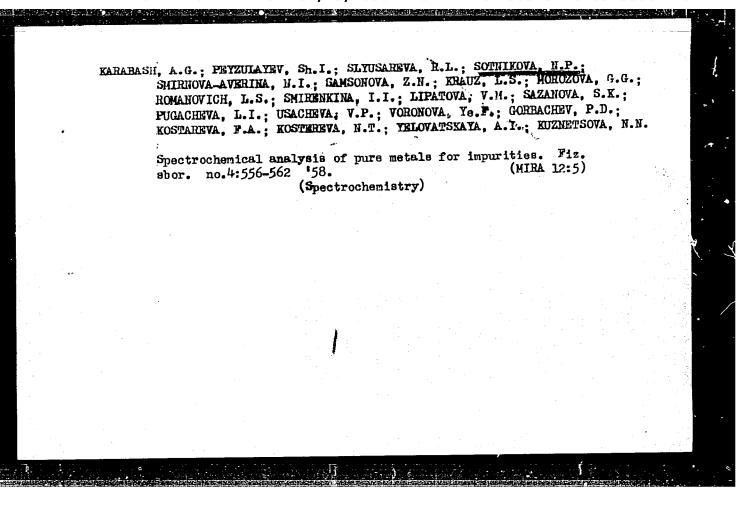
solutions were degassed by the freezing method. The formation of hydrazyls in electrochemical oxidation of the original compounds can be depicted by the scheme:

$$Ph_2N - NH - R + OH^-$$
 $Ph_2N - N - R + H_2O$ 
 $Ph_2N - N - R + Ph_2N - N - R + e$ .

Thus, the authors have shown that electrochemical oxidation as well as electrochemical reduction of compounds of the diphenylpicrylhydrazine type lead to the formation of free radicals, the properties and structure of which can be studied by the electron paramagnetic resonance method. [JPR5]

SUB CODE: 07 / SUBM DATE: 21Jun65 / ORIG REF: 006 / OTH REF: 004

Card 2/2 MC



KARABASH, A.G.; PEZULAYEV, Sh.I.; SOTNIKOVA, N.P.; SPZANOVA, S.K.

Determination of impurities in titanium and titanium dioxide. Trudy

Kom. anal. khim. 12:108-116 '60. (MIRA 13:8)

(Titanium—Analysis)

SOTNIKOVA, N.P.; ROMANOVICH, L.S.; PEYZULAYEV, Sh.I.; KARABASH, A.G.

Determination of impurities in zirconium. Trudy Kom. anal. khim. 12: (MIRA 13:8)

(Zirconium--Analysis)

APPROVED FOR RELEASE: 08/23/2000 CIA-RDP86-00513R001652530012-6"

SOTNIKOVA, N.S.

Use of the gelatin method for determining SiO2 in ash elements of plants. Fochvovedenie no.9:109-110 S \$54. (MIRA 17:12)

1. TSentral'nyy muzey pochvovedeniya imeni V.V. Dokuchayeva.

APPROVED FOR RELEASE: 08/23/2000 CIA-RDP86-00513R001652530012-6"

KAZARNOVSKIY, L.S.; LOKHVITSKAYA, M.F.; LYSENKO. L.V.; PIVNENKO, G.P.; SERGETENKO, T.A.; SILA, V.I.; SOTNIKOVA, O.M.; CHUYKO, O.V.

Comparison of methods for preparing and analysing infusions [with summary in English]. Apt.delo 8 no.1:64-71 Ja-F'59.

(MIRA 12:2)

1. Is Enar'kovskogo farmatsevticheskogo instituta (dir. - dots. fu.G. Borisyuk) Ministeretva zdravochraneniya USSR.

(EXTRACTS)

PIVNENKO, G.P. [Pivnenko, H.P.]; CHAGOVETS, R.K. [Ghahovets', R.K.]; PERTSEV, I.M.; SOTNIKOVA, O.M.

1. Khar'kovskiy farmatsevticheskiy institut.

PIVNENKO, G.P. [Pivnenke, H.P.]; SOTNIKOVA, O.M. [Sotnykova, O.M.]

Production of extracts from alkaloid-containing vegetable medicinal raw material under the effect of ultrasound. Farmatsev.zhur. 20 no.1:39-42 165. (MTRA 18:10)

**医线性神经炎性 1.5** 元代的 一元代代的 1.5 元代的 1.5 元

1. Kafedra tekhnologii lekarstv i galenovykh preparatov Khar'kovskogo farmatsevticheskogo instituta.

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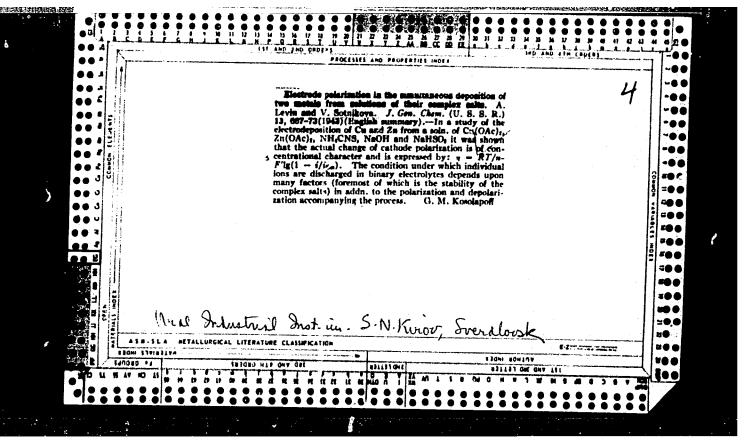
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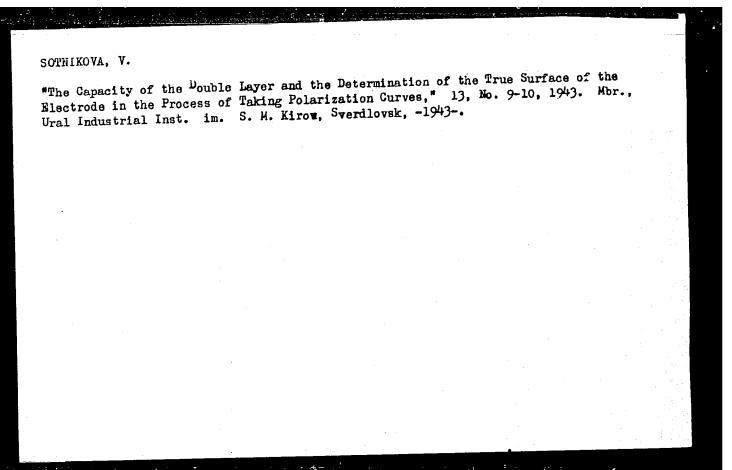
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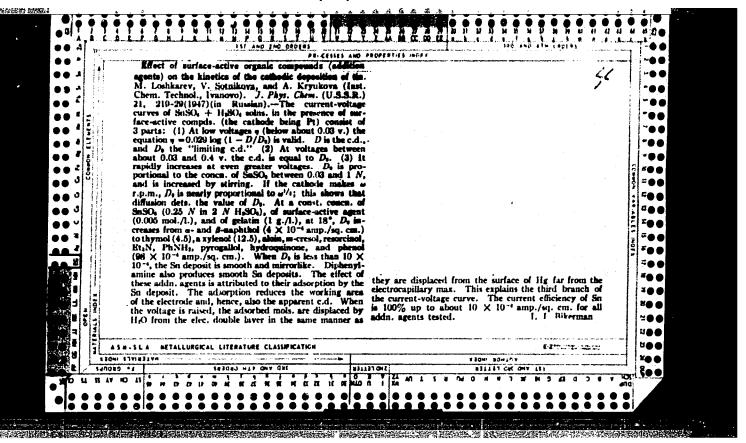
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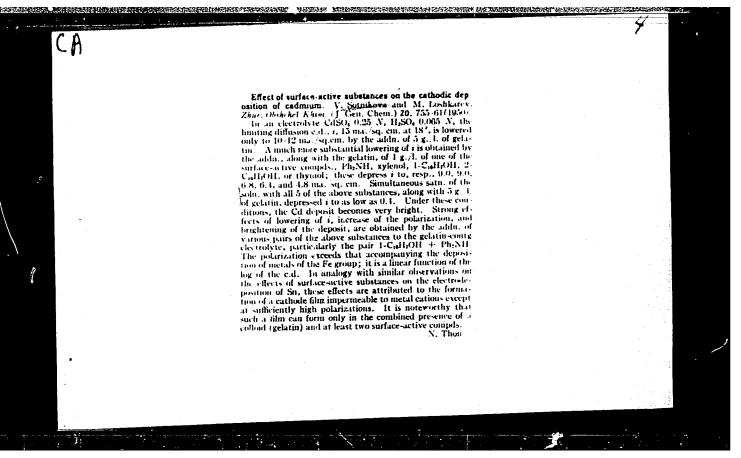
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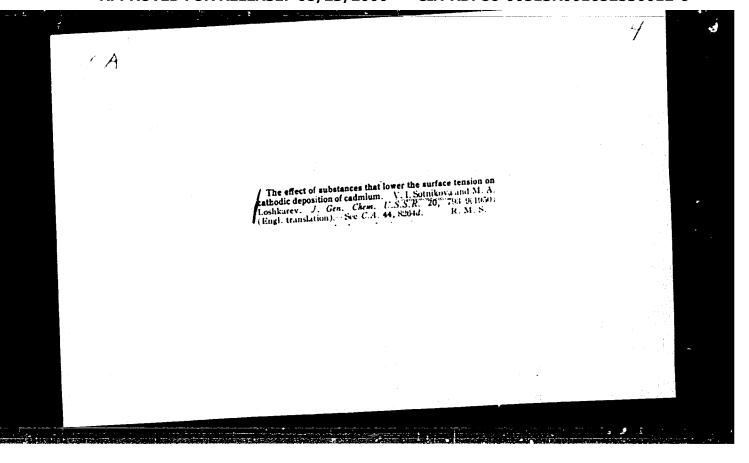
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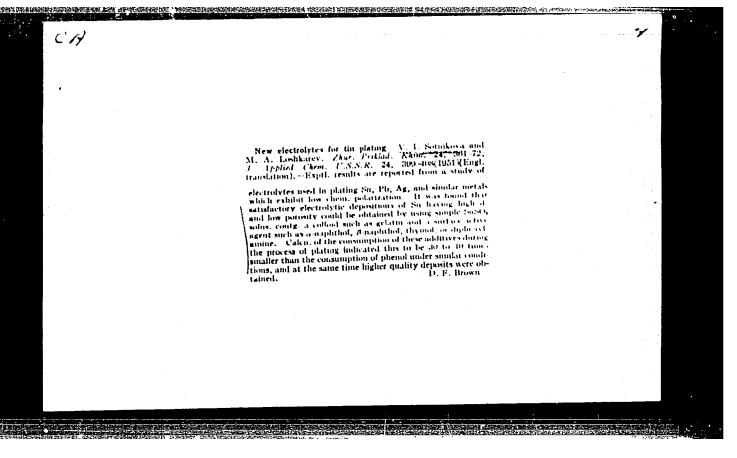








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S/073/60/026/004/013/018/XX Effect of H<sub>2</sub>O<sub>2</sub> Upon the Potential of the B023/B064 Oxygen Electrode on the Oxidized Surface of Steel in Alkaline Solution 10-15%  $\rm H_2O_2$  are decomposed within the first 2 hours. During 24 hours,  $\rm H_2O_2$ was almost completely decomposed. Contact with the electrode and increasing pH accelerate the decomposition. The experimentally confirmed dependence of the electrode potential of the passivated oxide steel in the solution saturated with air on the  $\mathrm{H_{2}O_{2}}$  concentration was expressed by the following equation:  $\psi$  = const - A log  $C_{H_2O_2}$ . Fig. 2 shows that the A values for experiments at which  $\psi$  was measured as a function of the increasing H202 concentration, were smaller than in experiments in which H202 decomposed. This may be explained by the fact that at repeated exactly dosed introduction of H<sub>2</sub>O<sub>2</sub>, the electrode continues oxidizing, and the potential of each point is shifted toward positive values. This shift is the stronger, the higher the  $H_2O_2$  concentration is, which may be seen from Fig. 4: At certain  $H_2O_2$  concentrations, the curve passes through a minimum and the sign of  $\Delta arphi$  is reversed. The collaborators A. N. Burmistrova and Ye. N. Chankova obtained for the oxidized steel electrode in 1.86 N NaOH solution Card 2/3

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